NSN 5962-01-372-6879

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View Online at https://aerobasegroup.com/nsn/5962-01-372-6879

view Offiline at https://aerobasegroup.com/nish/0302-01-3/2-00/3
Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
650.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
W/clock and 3-state output and w/enable and w/disable and asynchronous and bidirectional and erasable and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
60.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
600 gate epld
Voltage Rating And Type Per Characteristic:
-2.0 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
20.00 input picofarads and 20.00 output picofarads
Time Rating Per Chacteristic:
55.00 nanoseconds access
Memory Device Type:
Pal
Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:**

24 printed circuit

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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